





#### **60V PNP MEDIUM POWER TRANSISTOR IN SOT223**

#### **Features**

- BV<sub>CEO</sub> > -60V
- I<sub>C</sub> = -1A high Continuous Current
- Low saturation voltage V<sub>CE(sat)</sub> < -600mV @ -1A</li>
- Complementary NPN Type: FZT491
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>@3</a>
- Weight: 0.112 grams (approximate)

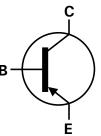
#### **Applications**

- Power MOSFET & IGBT gate driving
- Low loss power switching

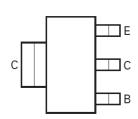
# SOT223







Device Symbol



Top View Pin-Out

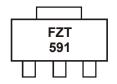
#### Ordering Information (Notes 4 & 5)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT591TA	FZT591	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com

### **Marking Information**



FZT591 = Product Type Marking Code





# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I <sub>CM</sub>	-2	Α
Base Current	I <sub>B</sub>	-200	mA

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	2	W
Fower Dissipation	(Note 6)	P <sub>D</sub>	3	W
Thermal Desistance Junction to Ambient	(Note 5)	Б	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7	$R_{ heta JL}$	19.41	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

# ESD Ratings (Note 8)

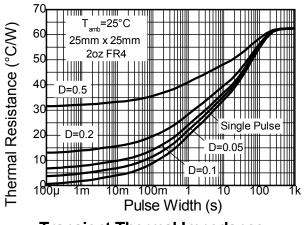
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

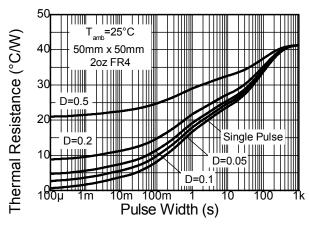
- 5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
- 6. Same as note (5), except the device is mounted on 50mm X 50mm single sided 2oz weight copper.
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



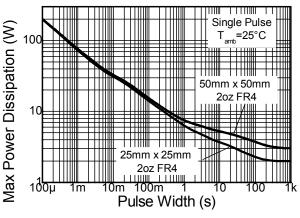
## **Thermal Characteristics and Derating Information**



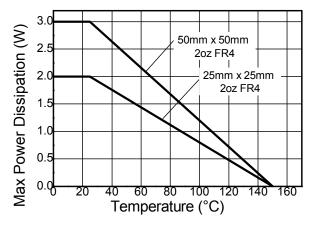
**Transient Thermal Impedance** 



**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



**Derating Curve** 





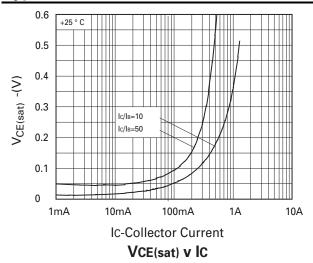
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

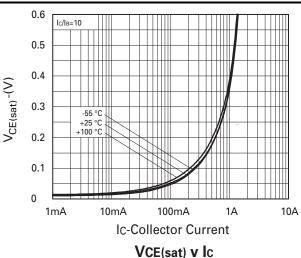
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-80	_	-	٧	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-60	_	_	٧	$I_C = -10 \text{mA}$
Emitter-Base Breakdown Voltage	$BV_EBO$	-7	8.1	-	V	$I_E = -100 \mu A$
Collector Cut-off Current	I <sub>CBO</sub>	-	<1	-100	nA	$V_{CB} = -60V$
Collector Cut-off Current	I <sub>CES</sub>	-	<1	-100	nA	V <sub>CES</sub> = -60V
Emitter Cut-off Current	I <sub>EBO</sub>	-	<1	-100	nA	$V_{EB} = -5.6V$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_ _	-175 -350	-300 -600	mV	$I_C = -500$ mA, $I_B = -50$ mA $I_C = -1$ A, $I_B = -100$ mA
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	-	965	-1200	mV	$I_C = -1A$ , $I_B = -100mA$
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	_	830	-1000	mV	$I_{C} = -1A$ , $V_{CE} = -5V$
DC current transfer Static ratio (Note 9)	h <sub>FE</sub>	100 100 80 15	220 175 155 40	300 - -	1	$I_{C}$ = -1mA, $V_{CE}$ = -5V $I_{C}$ = -500mA, $V_{CE}$ = -5V $I_{C}$ = -1A, $V_{CE}$ = -5V $I_{C}$ = -2A, $V_{CE}$ = -5V
Transitional Frequency (Note 9)	f <sub>T</sub>	150		-	MHz	$V_{CE} = -10V, I_{C} = -50mA$ f = 100MHz
Output Capacitance (Note 9)	C <sub>obo</sub>	-	=	10	pF	V <sub>CB</sub> = -10V. f = 1MHz

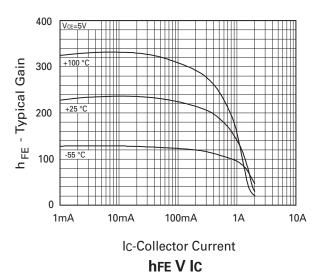
Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%

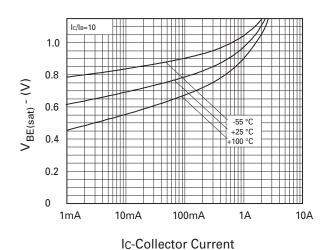


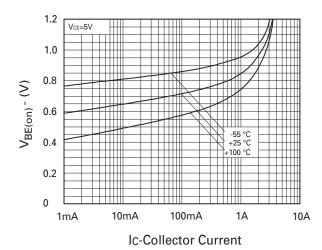
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

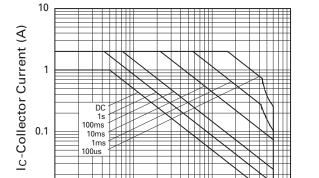












VBE(sat) v Ic

VCE - Collector Emitter Voltage (V)

Safe Operating Area

10V

1V

VBE(on) v IC Safe

0.01

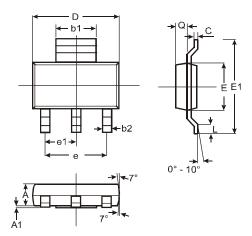
0.1V

100V



## **Package Outline Dimensions**

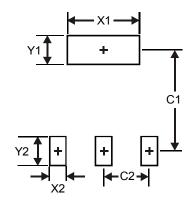
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b1	2.90	3.10	3.00			
b2	0.60	0.80	0.70			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
e	_		4.60			
e1			2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3





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